

Automotive Electronics Council

Component Technical Committee

Q100 Qualification Test Plan

Automotive Grade Level = 1 -40 to +125C

MSL = 3

| | | | | |
|----------------------------------|----------------------------------------------|----------------------------------------|-------------------------------------|-----------|
| Supplier Name: | Power Integrations | General Specification: | AEC-Q100 Rev. H | |
| Supplier Code: | N/A | Supplier Wafer Fabrication: | Lapis S2 (Miyagi, Japan) | |
| Supplier Part Number: | LNK3206GQ | Supplier Wafer Test: | N/A | |
| Supplier Contact: | Edward Ong | Supplier Assembly Site: | TSHT, China | |
| Supplier Family Type: | Integrated Circuit | Supplier Final Test Site: | TSHT, China | |
| Device Description: | Highly Energy Efficient Off-line Switcher IC | Supplier Reliability Signature: | Nick Stanco | |
| PPAP Submission Date: | TBD | Customer Test ID: | N/A | |
| Reason for Qualification: | New Part Qualification | Customer Part Number: | N/A | |
| Prepared by Signature: | Joseph Ho | Date: 05/03/20 | Customer Approval Signature: | N/A |
| | | | | Date: N/A |

| Test | # | Reference | Test Conditions | Lots | S.S. | Total | Results Lot/Pass/Fail | Comments: (N/A =Not Applicable) |
|------|---|-----------|-----------------|------|------|-------|--------------------------|------------------------------------|
|------|---|-----------|-----------------|------|------|-------|--------------------------|------------------------------------|

TEST GROUP A – ACCELERATED ENVIRONMENT STRESS TESTS

| | | | | | | | | |
|------------------------|----|----------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|----|-----|----------|--|
| PC | A1 | JESD22 A113 J-STD-020 | Preconditioning: (Test @ Rm) SMD only; Moisture Preconditioning for THB/HAST, AC/UHST, TC, & PTC; Peak Reflow Temp = 260°C | Min. MSL = 3 | | | MSL = 3 | |
| THB or HAST | A2 | JESD22 A101 JESD22 A110 | Temperature Humidity Bias: (Test @ Rm/Hot) 85°C / 85%R.H.; 1000 hours; Vd = 30V Highly Accelerated Stress Test: (Test @ Rm/Hot/) | 3 | 77 | 231 | 0 of 231 | |
| AC or UHST or TH | A3 | JESD22 A102 JESD22 A118 or JESD22-A101 | Autoclave: (Test @ Rm) Unbiased Highly Accelerated Stress Test: (Test @ Rm) Temperature Humidity without Bias: (Test @ Rm) 130°C / 85%R.H.; 96 hours | 3 | 77 | 231 | 0 of 231 | |
| TC | A4 | JESD22 A104 | Temperature Cycle: (Test @ Hot) -55°C to +150°C; 1000 Cycles | 3 | 77 | 231 | 0 of 231 | |
| PTC | A5 | JESD22 A105 | Power Temperature Cycle: (Test @ Rm/Hot) -40°C to +125°C; 1000 Cycles | 1 | 45 | 45 | 0 of 45 | |
| HTSL | A6 | JESD22 A103 | High Temperature Storage Life: (Test @ Rm/Hot) 150°C; 1000 Hours | 1 | 45 | 45 | 0 of 45 | |

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|------|---|-----------|-----------------|------|------|-------|-----------------------|---------------------------------|
|------|---|-----------|-----------------|------|------|-------|-----------------------|---------------------------------|

TEST GROUP B – ACCELERATED LIFETIME SIMULATION TESTS

| | | | | | | | | |
|------|----|--------------|-------------------------------------------------------------------------------------|---|-----|------|-----------|-----|
| HTOL | B1 | JESD22 A108 | High Temp Operating Life: (Test @ Rm/Cold/Hot) Tj = 125°C; 1000 hours; Vd = 580V | 3 | 77 | 231 | 0 of 231 | |
| ELFR | B2 | AEC-Q100-008 | Early Life Failure Rate: (Test @ Rm/Hot) Tj = 125°C; 48 hours; Vd = 600V | 3 | 800 | 2400 | 0 of 2400 | |
| EDR | B3 | AEC-Q100-005 | NVM Endurance & Data Retention Test: (Test @ Rm/Hot) | 3 | 77 | 231 | of | N/A |

TEST GROUP C – PACKAGE ASSEMBLY INTEGRITY TESTS

| | | | | | | | | |
|-----|----|-----------------------------------------|----------------------------------------------------------------------------------------------------|----------|--------------|----------|---------|-----|
| WBS | C1 | AEC-Q100-001 AEC-Q003 | Wire Bond Shear Test: (Cpk > 1.67) | 30 bonds | 5 parts Min. | 60 bonds | 0 of 60 | |
| WBP | C2 | Mil-STD-883, Method 2011 AEC-Q003 | Wire Bond Pull: (Cpk > 1.67); Each bonder used | 30 bonds | 5 parts Min. | 60 bonds | 0 of 60 | |
| SD | C3 | JESD22 B102 JSTD-002D | Solderability: (>95% coverage) 8hr steam aging prior to testing | 1 | 15 | 15 | 0 of 15 | |
| PD | C4 | JESD22 B100, JESD22 B108 AEC-Q003 | Physical Dimensions: (Cpk > 1.67) | 3 | 10 | 30 | 0 of 30 | |
| SBS | C5 | AEC-Q100-010 AEC-Q003 | Solder Ball Shear: (Cpk > 1.67); 5 balls from min. of 10 devices | 3 | 50 balls | | of | N/A |
| LI | C6 | JESD22 B105 | Lead Integrity: (No lead cracking or breaking); Through-hole only; 10 leads from each of 5 devices | 1 | 50 leads | | of | N/A |

TEST GROUP D – DIE FABRICATION RELIABILITY TESTS

| | | | | | | | | |
|------|----|-------------|--------------------------------------|---|---|---|---|-----------------------------------------------------------------------------------------------|
| EM | D1 | JESD61 | Electromigration: | - | - | - | 0 | Data Available 3 lots performed by Lapis S2; Total of 51 chips. |
| TDDB | D2 | JESD35 | Time Dependant Dielectric Breakdown: | - | - | - | 0 | Data Available 1 lot performed by Lapis S2; Total of 432 chips. |
| HCI | D3 | JESD60 & 28 | Hot Carrier Injection: | - | - | - | 0 | Data Available 3 lots performed by Lapis S2; Toal of 90 chips for LV and 125 chips for MV. |

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| Test | # | Reference | Test Conditions | Lots | S.S. | Total | Results Lot/Pass/Fail | Comments: (N/A =Not Applicable) |
|------|----|-------------------|----------------------------------------|------|------|-------|-----------------------|---------------------------------------------------------------------|
| NBTI | D4 | JESD90 | Negative Bias Temperature Instability: | - | - | - | 0 | Data Available 1 lot performed by Lapis S2; Total of 15 chips. |
| SM | D5 | JESD61, 87, & 202 | Stress Migration: | - | - | - | 0 | Data Available 5 lots performed by Lapis S2; Total of 318 chips. |

TEST GROUP E- ELECTRICAL VERIFICATION

| TEST | E1 | User/Supplier Specification | Pre and Post Stress Electrical Test: | All | All | All | 0 of All | |
|------|-----|----------------------------------|---------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|--------------------------------|----------------------------------------------------------------|
| HBM | E2 | AEC-Q100-002 | Electrostatic Discharge, Human Body Model: (Test @ Rm/Hot); (2KV HBM / Class 2 or better) | 1 | 12 | 12 | 0 of 12 ESD Level = 2 | Passed 500V, 1KV, 1.5KV, 2KV |
| CDM | E3 | AEC-Q100-011 | Electrostatic Discharge, Charged Device Model: (Test @ Rm/Hot); (750V corner leads, 500V all other leads / Class C4B or better) | 1 | 12 | 12 | 0 of 12 ESD Level = C3 | Passed 250V, 500V, 750V, 1KV |
| LU | E4 | AEC-Q100-004 | Latch-Up: (Test @ Rm/Hot) +125C | 1 | 6 | 6 | 0 of 6 | |
| ED | E5 | AEC-Q100-009 AEC-Q003 | Electrical Distributions: (Test @ Rm/Hot/Cold) (where applicable, Cpk >1.67) | 3 | 30 | 90 | 0 of 90 | |
| FG | E6 | AEC-Q100-007 | Fault Grading: | - | - | - | Fault Grade Other (explain) | N/A |
| CHAR | E7 | AEC-Q003 | Characterization: (Test @ Rm/Hot/Cold) | - | - | - | PPAP Data | |
| EMC | E9 | SAE J1752/3 | Electromagnetic Compatibility (Radiated Emissions) | 1 | 1 | 1 | | Estimated Completion Date = July 2020; Non-Gating requirement. |
| SC | E10 | AEC Q100-012 | Short Circuit Characterization | 3 | 10 | 30 | | N/A |
| SER | E11 | JESD89-1 JESD89-2 JESD89-3 | Soft Error Rate | 1 | 3 | 3 | | N/A |
| LF | E12 | AEC-Q005 | Lead (Pb) Free: (see AEC-Q005) | - | - | - | Done | Passed |

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|------|---|-----------|-----------------|------|------|-------|--------------------------|------------------------------------|

TEST GROUP F – DEFECT SCREENING TESTS

| | | | | | | | | |
|-----|----|----------|------------------------------------------------|-----|-----|-----|-------------------------------|--|
| PAT | F1 | AEC-Q001 | Process Average Testing: (see AEC-Q001) | All | All | All | Reject units outside Avg. | |
| SBA | F2 | AEC-Q002 | Statistical Bin/Yield Analysis: (see AEC-Q002) | All | All | All | Reject units outside criteria | |

TEST GROUP G – CAVITY PACKAGE INTEGRITY TESTS (for Ceramic Package testing only)

| | | | | | | | | |
|------|----|----------------------------|-----------------------------------------------------------------------------------------------------------------------------------|---|----|----|----|-----|
| MS | G1 | JESD22 B104 | Mechanical Shock: (Test @ Rm) | 1 | 15 | 15 | of | N/A |
| VFV | G2 | JESD22 B103 | Variable Frequency Vibration: (Test @ Rm) | 1 | 15 | 15 | of | N/A |
| CA | G3 | MIL-STD-883 Method 2001 | Constant Acceleration: (Test @ Rm) | 1 | 15 | 15 | of | N/A |
| GFL | G4 | MIL-STD-883 Method 1014 | Gross and Fine Leak: | 1 | 15 | 15 | of | N/A |
| DROP | G5 | ----- | Drop Test: (Test @ Rm) MEMS cavity parts only. Drop part on each of 6 axes once from a height of 1.2m onto a concrete surface. | 1 | 5 | 5 | of | N/A |
| LT | G6 | MIL-STD-883 Method 2004 | Lid Torque: | 1 | 5 | 5 | of | N/A |
| DS | G7 | MIL-STD-883 Method 2019 | Die Shear: | 1 | 5 | 5 | of | N/A |
| IWV | G8 | MIL-STD-883 Method 1018 | Internal Water Vapor: | 1 | 3 | 3 | of | N/A |